NSN 5961-01-537-6681

Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-537-6681 **Inclosure Material:** Glass **Overall Length:** 1.650 inches **End Application:** 0a-923 (v) /g operations group fixed **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 37.8 breakdown voltage, dc and 30.8 working peak reverse voltage **Current Rating Per Characteristic:** 1.00 milliamperes forward current, average peak **Product Name:** Semiconductor device assembly **Special Features:** Includes semiconductor device diode 1n5646a, terminal lugs, insulation slvg, elec. **Nuclear Hardness Critical Feature:** Hardened Shelf Life: N/a **Unit Of Measure: Demilitarization:** No